



<u>Atsufumi Hirohata</u> Department of Electronics

THE UNIVERSITY of York



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Contents of Introductory Nanotechnology

First half of the course :

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Basic condensed matter physics

1. Why *solids* are *solid*?

2. What is the most common atom on the earth?

- 3. How does an electron travel in a material ?
- 4. How does lattices vibrate thermally ?
- 5. What is a semi-conductor ?
- 6. How does an electron tunnel through a barrier ?
- 7. Why does a magnet attract / retract ?
- 8. What happens at interfaces ?

Second half of the course :

Introduction to nanotechnology (nano-fabrication / application)

What Is the Most *Common Atom* on the earth?

- Phase diagram
- Free electron model
 - Electron transport
 - Degeneracy
 - Electron Potential
 - Brillouin Zone
 - Fermi Distribution





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Civilization" Today

-based products around us :

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Major Phases of Fe

Fe changes the crystalline structures with temperature / pressure :





Free Electron Model

Equilibrium state :

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Free electrons :

mass m_i charge -q and velocity v_i Equation of motion along E:

$$m\frac{dv_i}{dt} = -qE$$

Average over free electrons : drift velocity : v_d

For each free electron :

thermal velocity (after collision) : v_{0i} acceleration by E for τ_i

$$v_i = v_{0i} = -\frac{q}{m} \boldsymbol{E} \boldsymbol{\tau}_i$$

Average over free electrons :

collision time : τ

$$v_{\rm d} = -\frac{q\tau}{m}E$$

Using a number density of electrons *n*, current density *J* :

$$\boldsymbol{J} = \left(-v_{\rm d}\right)q\boldsymbol{n} = q^2 \frac{n}{m} \boldsymbol{E}\boldsymbol{n}$$

Ohm's law :

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$$V = iR = i\frac{\rho\ell}{S}$$
 For a small area : $\Delta V = \Delta i\rho\frac{\Delta\ell}{\Delta S} \rightarrow \frac{\Delta V}{\Delta\ell} = \rho\frac{\Delta i}{\Delta S} \rightarrow E = \rho J$

where ρ : electric resistivity (electric conductivity : σ = 1 / ρ)

By comparing with the free electron model :

$$J = q^2 \frac{n}{m} E\tau$$
$$\sigma = \frac{1}{\rho} = q^2 \frac{n}{m} \tau$$

Relaxation Time

Resistive force by collision :

X

$$\begin{array}{c} + \\ + \\ \tau \\ + \\ + \\ + \\ \end{array}$$

Equation of motion : with resistive force mv / τ

$$m\frac{dv}{dt} = -qE - \frac{m}{\tau}v$$

For the initial condition :

$$v = 0$$
 at $t = 0$

$$v = -\frac{q\tau}{m} E \Big[1 - \exp(-t/\tau) \Big]$$

For a steady state $(t >> \tau)$,

$$v = -\frac{q\tau}{m}E$$

 τ : collision time

If *E* is removed in the equation of motion :

$$m\frac{dv}{dt} = -\frac{m}{\tau}v$$

For the initial condition :

$$v = v_{d}$$
 at $t = 0$
 $v = v_{d} \exp(-t/\tau)$



Also,

Equation of motion under *E* :

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$$m\frac{dv}{dt} = -qE$$

For an electron at $r_{,}$

collision at t = 0 and $r = r_0$ with v_0 Accordingly,

$$\boldsymbol{r} - \boldsymbol{r}_0 = \boldsymbol{v}_0 t + \frac{1}{2} \frac{(-q)\boldsymbol{E}}{m} t^2$$

Here, ergodic assumption :

temporal mean = ensemble mean

$$\frac{\langle \boldsymbol{r} - \boldsymbol{r}_0 \rangle}{\frac{\langle \boldsymbol{r} - \boldsymbol{r}_0 \rangle}{\tau}} = \frac{-q\boldsymbol{E}}{m}\boldsymbol{\tau}^2$$
$$\frac{\langle \boldsymbol{r} - \boldsymbol{r}_0 \rangle}{\tau} = \frac{-q\boldsymbol{\tau}}{m}\boldsymbol{E} = \boldsymbol{v}_d$$

 $\left\langle t^{2}\right\rangle = \int_{0}^{\infty} \frac{t^{2}}{\tau} \exp\left(-\frac{t}{\tau}\right) dt = 2\tau^{2}$

therefore, by taking an average over Finally, $v_d = -\mu E$ is obtained. non-collided short period, $\mu = q\tau / m$: mobility

$$\langle \boldsymbol{r} - \boldsymbol{r}_0 \rangle = \langle \boldsymbol{v}_0 t \rangle + \frac{-q\boldsymbol{E}}{2m} \langle t^2 \rangle$$

Since t and v_0 are independent,

$$\left< \boldsymbol{v}_0 t \right> = \left< \boldsymbol{v}_0 \right> \left< t \right>$$

Here, $\langle \mathbf{v}_0 \rangle = 0$, as v_0 is random.





Electron potential energy : V = -A / r



Periodic Potential in a Crystal

Potential energy in a crystal (e.g., N Na atoms) :



Electron potential energy

- Potential energy changes the shape inside a crystal.
- 3s state forms N energy levels \rightarrow Conduction band



Wave / particle duality of an electron :

Wave nature of electrons was predicted by de Broglie,

and proved by Davisson and Germer.

Ni crystal		Particle nature	Wave nature
	Kinetic energy	$mv^2/2$	$h\nu = \hbar\omega$
electron beam	Momentum	mv	$h/\lambda = \hbar k$

$$\lambda = \frac{h}{p} = \frac{h}{mv}$$
 (*h* : Planck's constant)

 $\hbar = h/2\pi, \ \omega = 2\pi v, \ k = 2\pi/\lambda$







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Reciprocal lattice :



3D Brillouin Zone



Figure 1 Free electron Fermi surfaces for fcc metals with one (Cu) and three (Al) valence electrons per primitive cell. The Fermi surface shown for copper has been deformed from a sphere to agree with the experimental results. The second zone of aluminum is nearly half-filled with electrons. (A. R. Mackintosh.)

* C. Kittel, Introduction to Solid State Physics (John Wiley & Sons, New York, 1986).



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Pauli exclusion principle

At temperature T, probability that one energy state E is occupied by an electron :



Fermi-Dirac / Maxwell-Boltzmann Distribution

Electron number density :



(small electron number density) (large electron number density)

* M. Sakata, Solid State Physics (Baifukan, Tokyo, 1989).

Fermi wave number $k_{\rm F}$ represents $E_{\rm F}$:

Fermi velocity :
$$v_{\rm F} = \sqrt{\frac{2E_{\rm F}}{m}}$$

 $k_{\rm F} = \frac{m}{\hbar} v_{\rm F} = \frac{\sqrt{2mE_{\rm F}}}{\hbar}$

Under an electrical field :

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Electrons, which can travel, has an energy of ~ $E_{\rm F}$ with velocity of $v_{\rm F}$ For collision time τ , average length of electrons path without collision is

 $\ell = v_F \tau$ Mean free path

Density of states :

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Number of quantum states at a certain energy in a unit volume

$$g(E) = 2\frac{1}{(2\pi)^{3}} \frac{4\pi}{2} \left(\frac{2m}{\hbar^{2}}\right)^{3/2} \sqrt{E} dE$$



Density of States (DOS) and Fermi Distribution

Carrier number density n is defined as :

